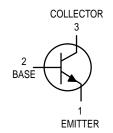
Amplifier Transistor NPN Silicon

MPS6428





MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	50	Vdc
Collector-Base Voltage	VCBO	60	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current — Continuous	IC	200	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (IC = 1.0 mAdc, IB = 0)	V(BR)CEO	50	_	Vdc		
Collector-Base Breakdown Voltage (I _C = 0.1 mAdc, I _E = 0)	V(BR)CBO	60	_	Vdc		
Collector Cutoff Current (VCE = 30 Vdc)	ICES	_	0.025	μΑ		
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	ICBO	_	0.01	μΑ		
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ Vdc}, I_{C} = 0$)	IEBO	_	0.01	μΑ		

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

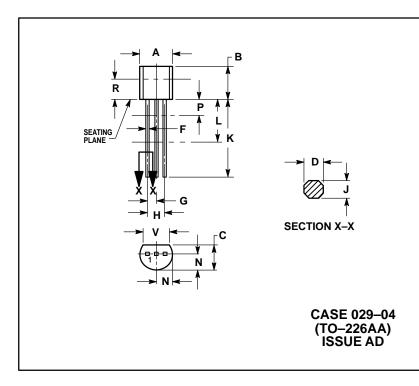
Characteristic	Symbol	Min	Max	Unit	
ON CHARACTERISTICS					
DC Current Gain	hFE	250 250 250 250 250	 650 	_	
Collector-Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 0.5 \text{ mAdc}$) ($I_C = 100 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)	VCE(sat)	_	0.2 0.6	Vdc	
Base-Emitter On Voltage (IC = 1.0 mAdc, VCE = 5.0 Vdc)	VBE(on)	0.56	0.66	Vdc	
SMALL-SIGNAL CHARACTERISTICS	•				
Current-Gain — Bandwidth Product (IC = 1.0 mAdc, V_{CE} = 5.0 V, f = 100 MHz)	f _T	100	700	MHz	
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	3.0	pF	
Input Capacitance (VEB = 0.5 Vdc, I _C = 0, f = 1.0 MHz)	C _{ibo}	_	8.0	pF	
Input Impedance (IC = 1.0 mAdc, VCE = 5.0 Vdc, f = 1.0 kHz)	h _{ie}	3.0	30	kΩ	
Voltage Feedback Ratio (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc, f = 1.0 kHz)	h _{re}	2.0	20	X 10 ⁻⁴	
Small–Signal Current Gain (IC = 1.0 mAdc, VCE = 5.0 Vdc, f = 1.0 kHz)	h _{fe}	200	800	_	
Output Admittance (IC = 1.0 mAdc, VCE = 5.0 Vdc, f = 1.0 kHz)	h _{Oe}	5.0	50	μmhos	

NOISE FIGURE/TOTAL NOISE VOLTAGE CHARACTERISTICS

	NF Max	VT (1)	NF Max	VT (2)	NF Max	VT (3)	Ur	nit
Noise Figure/Voltage ($V_{CE} = 5.0 \text{ V}$, $I_{C} = 0.1 \text{ mA}$, $T_{A} = 25^{\circ}\text{C}$)	7.0	18.1	6.0	5700	3.5	4.3	dB	nV

^{1.} $R_S = 10 \text{ k}\Omega$, BW = 1.0 Hz, f = 100 Hz 2. $R_S = 50 \text{ k}\Omega$, BW = 15.7 kHz, f = 10 Hz–10 kHz 3. $R_S = 500 \Omega$, BW = 1.0 Hz, f = 10 Hz

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
V	0.135		3 43		

STYLE 1: PIN 1. EMITTER

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